

TOSHIBA Transistor Silicon PNP Epitaxial Type (PCT Process) Silicon NPN Epitaxial Type (PCT Process)

HN1B01F

Audio Frequency General Purpose Amplifier Applications

Unit: mm

Q1:

- High voltage and high current
 - $: V_{CEO} = -50 \text{ V}, I_C = -150 \text{ mA (max)}$
- High h_{FE} : $h_{FE} = 120$ to 400
- Excellent hfe linearity

 $: h_{FE} (I_C = -0.1 \text{ mA}) / h_{FE} (I_C = -2 \text{ mA}) = 0.95 \text{ (typ.)}$

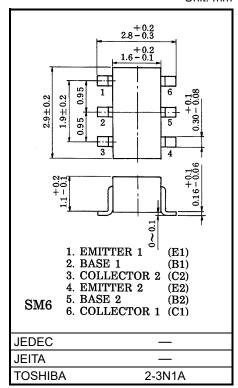
Q2:

- High voltage and high current
 - $: V_{CEO} = 50 \text{ V}, I_{C} = 150 \text{ mA (max)}$
- High h_{FE} : $h_{FE} = 120$ to 400
- Excellent hFE linearity

 $: h_{FE} (I_C = 0.1 \text{ mA}) / h_{FE} (I_C = 2 \text{ mA}) = 0.95 \text{ (typ.)}$

Q1 Absolute Maximum Ratings (Ta = 25°C)

Characteristic	Symbol	Rating	Unit
Collector-base voltage	V _{CBO}	-50	V
Collector-emitter voltage	VCEO	-50	V
Emitter-base voltage	V _{EBO}	-5	V
Collector current	Ic	-150	mA
Base current	ΙΒ	-50	mA



Weight: 0.015 g (typ.)

Q2 Absolute Maximum Ratings (Ta = 25°C)

Characteristic	Symbol	Rating	Unit
Collector-base voltage	Vсво	60	V
Collector-emitter voltage	VCEO	50	V
Emitter-base voltage	VEBO	5	V
Collector current	Ic	150	mA
Base current	lΒ	30	mA

Start of commercial production 1989-02



Q1, Q2 Common Absolute Maximum Ratings (Ta = 25°C)

Characteristic	Symbol	Rating	Unit	
Collector power dissipation	Pc*	300	mW	
Junction temperature	T _j (Note 1)	150	°C	
	T _j (Note 2)	125		
Storage temperature range	T _{stg} (Note 1)	−55 to 150	°C	
	T _{stg} (Note 2)	−55 to 125		

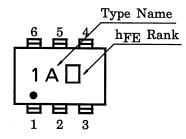
Note: Using continuously under heavy loads (e.g. the application of high temperature/current/voltage and the significant change in temperature, etc.) may cause this product to decrease in the reliability significantly even if the operating conditions (i.e. operating temperature/current/voltage, etc.) are within the absolute maximum ratings.

Please design the appropriate reliability upon reviewing the Toshiba Semiconductor Reliability Handbook ("Handling Precautions"/"Derating Concept and Methods") and individual reliability data (i.e. reliability test report and estimated failure rate, etc).

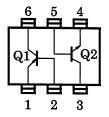
*: Total rating

Note 1: For devices with the ordering part number ending in LF(T. Note 2: For devices with the ordering part number in other than LF(T.

Marking



Equivalent Circuit (Top View)





Q1 Electrical Characteristics (Ta = 25°C)

Characteristic	Symbol	Test Condition	Min	Тур.	Max	Unit
Collector cut-off current	Ісво	VcB = −50 V, IE = 0 A	_	_	-0.1	μΑ
Emitter cut-off current	IEBO	V _{EB} = −5 V, I _C = 0 A	_	_	-0.1	μA
DC current gain	hFE (Note)	VCE = −6 V, IC = −2 mA	120	_	400	_
Collector-emitter saturation voltage	VCE (sat)	I _C = −100 mA, I _B = −10 mA	_	-0.1	-0.3	V
Transition frequency	fŢ	VCE = −10 V, IC = −1 mA	_	120	_	MHz
Collector output capacitance	Cob	V _{CB} = −10 V, I _E = 0 A, f = 1 MHz	_	4	_	pF

Q2 Electrical Characteristics (Ta = 25°C)

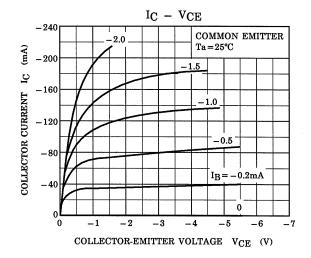
Characteristic	Symbol	Test Condition	Min	Тур.	Max	Unit
Collector cut-off current	ICBO	V _{CB} = 60 V, I _E = 0 A	_	_	0.1	μΑ
Emitter cut-off current	IEBO	VEB = 5 V, IC = 0 A	_	_	0.1	μA
DC current gain	hFE (Note)	V _{CE} = 6 V, I _C = 2 mA	120	_	400	_
Collector-emitter saturation voltage	V _{CE} (sat)	I _C = 100 mA, I _B = 10 mA	_	0.1	0.25	V
Transition frequency	f⊤	V _{CE} = 10 V, I _C = 1 mA	_	150	_	MHz
Collector output capacitance	C _{ob}	V _{CB} = 10 V, I _E = 0 A, f = 1 MHz	_	2	_	pF

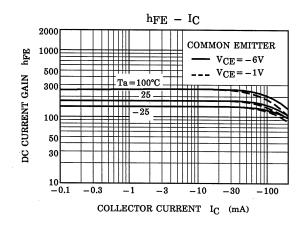
Note: hFE Classification Y (Y): 120 to 240, GR (G): 200 to 400

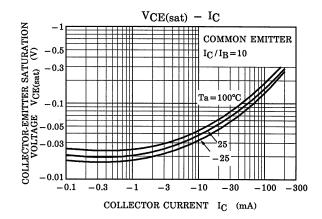
() Marking symbol

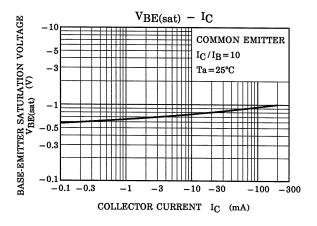


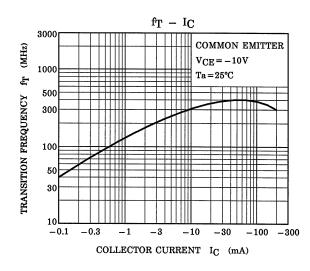
Characteristics Curves Q1 (PNP Transistor)

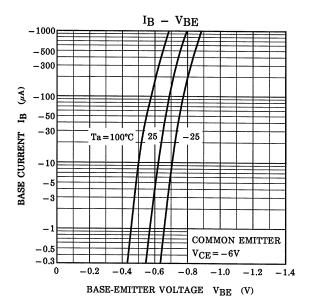








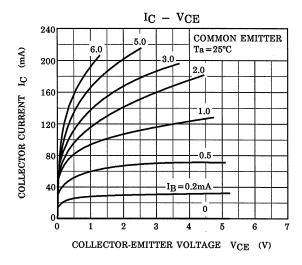


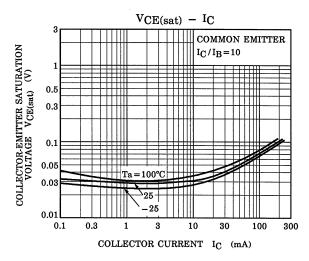


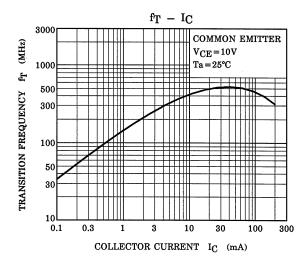
The above characteristics curves are presented for reference only and not guaranteed by production test, unless otherwise noted.

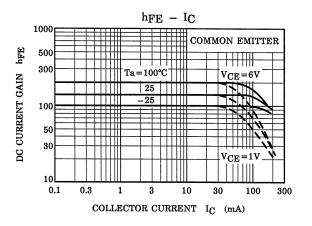


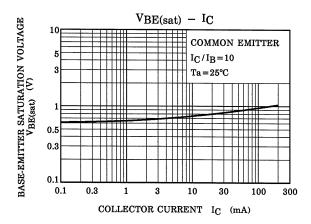
Characteristics Curves Q2 (NPN Transistor)

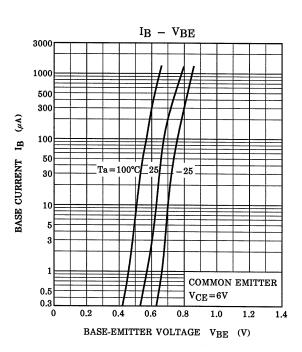








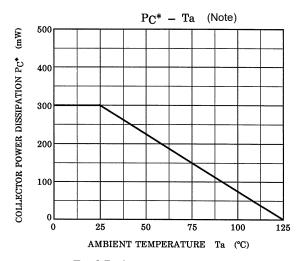




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Characteristics Curves (Q1, Q2 Common)



* : Total Rating

Note: Reference only with T_j of 125 $\,^{\circ}\!\!$ C.

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